



DMT32M5LFG

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
	1.7mΩ @ V _{GS} = 10V	100A
30V	2.8mΩ @ V _{GS} = 4.5V	100A

Description

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$, yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Backlighting
- Power Management Functions
- DC-DC Converters

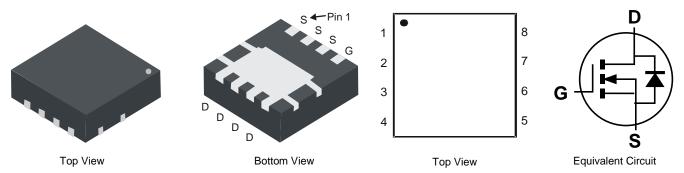
30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Features and Benefits

- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- Excellent Q_{gd} × R_{DS(ON)} Product (FOM)
- Advanced Technology for DC-DC Converts
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- 100% UIS (Avalanche) Rated
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: PowerDl[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminal Finish Matte Tin Annealed Over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
 - Weight: 0.008 grams (Approximate)
- PowerDI3333-8



Ordering Information (Note 4)

Part Number	Case	Packaging
DMT32M5LFG-7	PowerDI3333-8	2,000/Tape & Reel
DMT32M5LFG-13	PowerDI3333-8	3,000/Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



SK2 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17 = 2017) WW = Week Code (01 to 53)

See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and



Maximum Ratings (@T_C = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	30	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Note 6) V_{GS} = 10V	T _C = +25°C T _C = +70°C	ID	100 100	А
Continuous Drain Current (Note 5) $V_{GS} = 10V$	T _A = +25°C T _A = +70°C	ID	30 24	А
Maximum Continuous Body Diode Forward Current (Note 5)		Is	2.8	A
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)	IDM	350	A	
Pulsed Body Diode Forward Current (380µs Pulse, Duty Cycle	I _{SM}	350	А	
Avalanche Current, L = 0.1mH	I _{AS}	46.7	A	
Avalanche Energy, L = 0.1mH	EAS	109	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 5)		R _{θJA}	54	°C/W
Total Power Dissipation (Note 6) $T_{C} = +25^{\circ}C$		PD	50	W
Thermal Resistance, Junction to Case (Note 6)		R _{θJC}	2.5	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_J = +25°C, unless otherwise specified.)

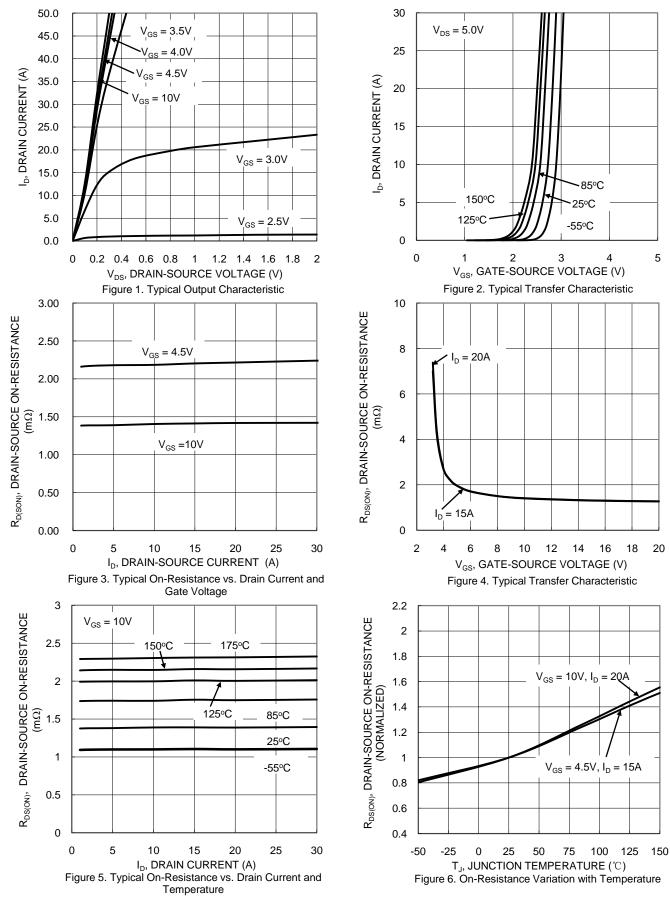
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	,		51				
Drain-Source Breakdown Voltage	BV _{DSS}	30		_	V	$V_{GS} = 0V, I_D = 1mA$	
Zara Cata Valtaga Drain Current		_	—	1	μA	$V_{DS} = 24V, V_{GS} = 0V$	
Zero Gate Voltage Drain Current	I _{DSS}			10		$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	lasa			±10	μA	$V_{GS} = 20V, V_{DS} = 0V$	
	I _{GSS}	_				$V_{GS} = -16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)					-		
Gate Threshold Voltage	V _{GS(TH)}	1	1.4	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
		_	1.4	1.7	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	2.1	2.8	11152	$V_{GS} = 4.5V, I_D = 15A$	
	NDS(ON)	—	1.9	2.6	mΩ	V _{GS} = 10V, I _D = 20A, T _J = +125°C (Note 8)	
Diode Forward Voltage	V _{SD}	_	0.7	1	V	$V_{GS} = 0V, I_{S} = 2A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}		4066			$V_{DS} = 15V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss		1736	-	pF		
Reverse Transfer Capacitance	C _{rss}		333				
Gate Resistance	R _g		0.71		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg		34				
Total Gate Charge (V _{GS} = 10V)	Qg		67.7		nC	V _{DS} = 15V, I _D = 20A	
Gate-Source Charge	Q _{gs}		8	-	ne		
Gate-Drain Charge	Q _{gd}	_	15	_			
Turn-On Delay Time	t _{D(ON)}	_	7.2	_		$V_{DD} = 15V, V_{GS} = 10V,$ $R_G = 3\Omega, I_D = 20A$	
Turn-On Rise Time	t _R		13.2	_	nc		
Turn-Off Delay Time	t _{D(OFF)}		37.4	_	ns		
Turn-Off Fall Time	tF		23.9				
Bodyy Diode Reverse Recovery Time	t _{RR}		28.7	_	ns		
Body Diode Reverse Recovery Charge	Q _{RR}	_	45.8	_	nC	I _F = 15A, di/dt = 500A/μs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect. Notes:

8. Guaranteed by design. Not subject to product testing.

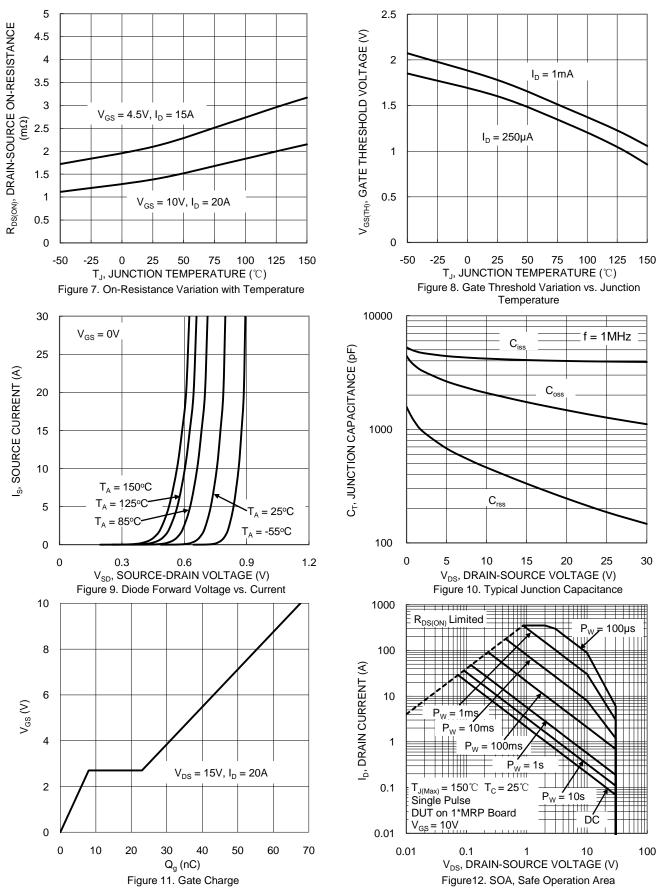


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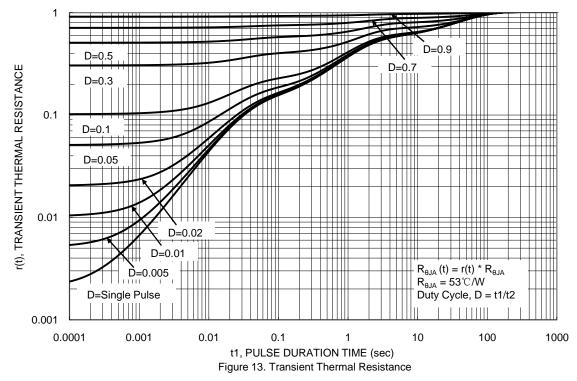




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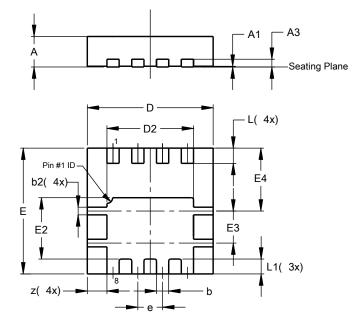




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

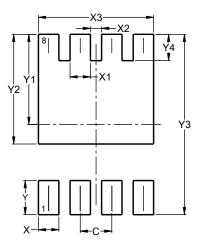


PowerDI3333-8						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	1	-	0.203			
b	0.27	0.37	0.32			
b2	0.15	0.25	0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
Е	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
E3	0.79	0.89	0.84			
E4	1.60	1.70	1.65			
е	-	-	0.65			
L	0.35	0.45	0.40			
L1	_	_	0.39			
z	_	-	0.515			
All I	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)			
С	0.650			
Х	0.420			
X1	0.420			
X2	0.230			
X3	2.370			
Y	0.700			
Y1	1.850			
Y2	2.250			
Y3	3.700			
Y4	0.540			



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